NSN 5961-01-173-2694

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Height:
0.165 inches
Overall Width:
0.205 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 reverse gate to source voltage
Current Rating Per Characteristic:
200.00 milliamperes forward current, total rms nanoamperes and 50.00 milliamperes source cutoff current minor
Power Rating Per Characteristic:
375.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0